

Product Change Notice

PCN: PCN_KSM26RS8_8MEI_C1 Date: February 3, 2020 Kingston Technology Company 17600 Newhope Street Fountain Valley, CA 92708 USA

kinasta

| Type of Change: | DRAM Marking Change |
|------------------------|--|
| Part Number: | KSM26RS8/8MEI |
| BOM: | 9965690-014.A00G |
| Product Description: | 8GB DDR4-2666 ECC Registered DIMM CL19 1Rx8 1.2V Micron E w/IDT Register |
| JEDEC Specification: | 8GB 1Rx8 PC4-2666V-RD1-12 |
| Description of Change: | Due to supply changes and to reflect market conditions, a DRAM speed grade allowance (2666MHz to 3200MHz) is authorized for Server Premier parts using the same DRAM die revision of Micron E: |
| | MT40A1G8SA- <u>075</u> :E to MT40A1G8SA- <u>062</u> E:E |
| | Micron E 3200 grade (062) DRAM to be allowed to substitute 2666/2400 (075) grade. Faster DRAM grade is backwards compatible, no BOM change or requalification required. |